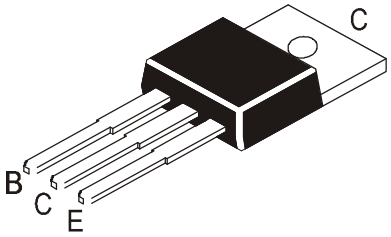
SILICON EPITAXIAL POWER TRANSISTORS

MJE15032 NPN
MJE15033 PNP



TO - 220
Plastic Package

High - Frequency Drivers in Audio Amplifier

ABSOLUTE MAXIMUM RATINGS

DESCRIPTION	SYMBOL	VALUE	UNIT
Collector- Base Voltage	V_{CBO}	250	V
Collector- Emitter Voltage	V_{CEO}	250	V
Emitter- Base Voltage	V_{EBO}	5	V
Collector Current Continuous Peak	I_C	8 16	A
Base Current	I_B	2	A
Power Dissipation T_C=25ºC Derate Above 25ºC	P_D	50 0.4	W W/ºC
Power Dissipation T_A=25ºC Derate Above 25ºC	P_D	2 0.016	W W/ºC
Operating & Storage Junction Temperature Range	$T_{j, Tstg}$	- 65 to +150	ºC

Thermal Resistance

Thermal Ambient	$R_{th\ (j-a)}$	62.5	ºC/W
Junction to Case	$R_{th\ (j-c)}$	2.5	ºC/W

ELECTRICAL CHARACTERISTICS (Tc=25º C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	TYP	MAX	UNIT
Collector- Emitter Sustaing Voltage	$V_{CEO(sus)}$*	I_C=10mA, I_B=0	250	-	-	V
Collector Cut Off Current	I_{CBO}	V_{CB}=150V, I_E=0	-	-	10	µA
Emitter Cut Off Current	I_{EBO}	V_{BE}=5V, I_C=0	-	-	10	µA
DC Current Gain	h_{FE}*	I_C=0.5A, V_{CE}=5V I_C=1.0A, V_{CE}=5V I_C=2A, V_{CE}=5V	50 50 10	- - -	- - -	
Collector Emitter Saturation Voltage	$V_{CE(sat)}$ *	I_C=1A, I_B=0.1A	-	-	0.5	V
Base Emitter on Voltage	$V_{BE(on)}$ *	I_C=1.0A, V_{CE}=5V	-	-	1.0	V

Dynamic Characteristics

Current Gain - Bandwidth Product	f_T **	I_C=500mA, V_{CE}=10V f_{test}=1MHz	30	-	-	MHz

*** Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤2 %**

**** f_T= $|h_{fe}|$. f_{test}.**

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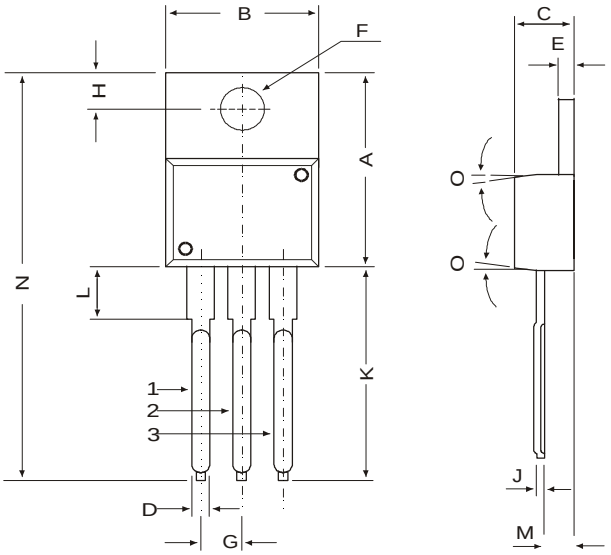
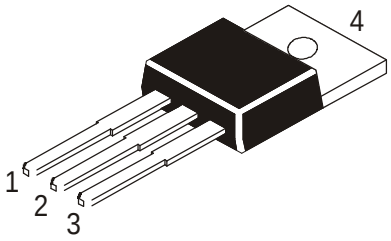


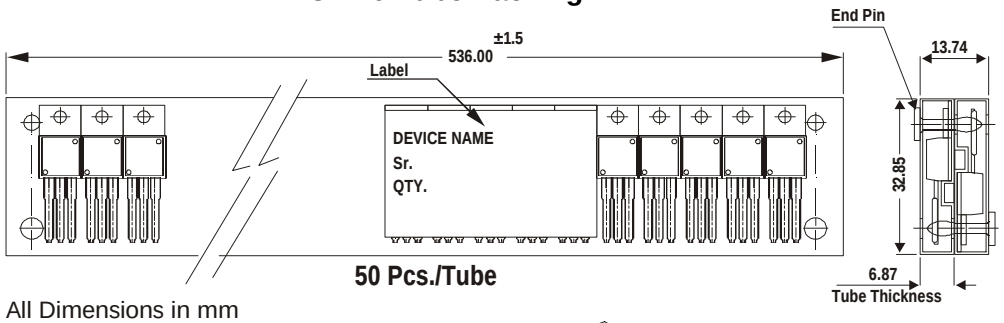
DIM	MIN	MAX
A	14.42	16.51
B	9.63	10.67
C	3.56	4.83
D	—	0.90
E	1.15	1.40
F	3.75	3.88
G	2.29	2.79
H	2.54	3.43
J	—	0.56
K	12.70	14.73
L	2.80	4.07
M	2.03	2.92
N	—	31.24
O	7 DEG	

All diminsions in mm.



Pin Configuration
1. Base
2. Collector
3. Emitter
4. Collector

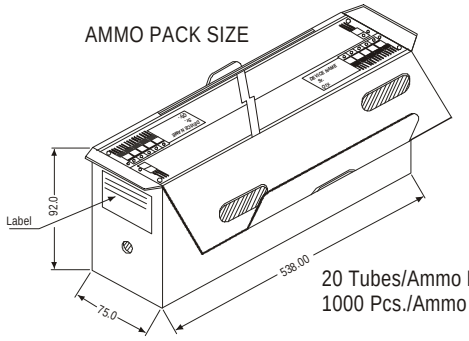
TO-220 Tube Packing



50 Pcs./Tube

All Dimensions in mm

AMMO PACK SIZE



20 Tubes/Ammo Pack
1000 Pcs./Ammo Pack

Packing Detail

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-220	200 pcs/polybag	396 gm/200 pcs	3" x 7.5" x 7.5"	1K	17" x 15" x 13.5"	16K	36 kgs
	50 pcs/tube	135 gm/50 pcs	3.5" x 3.7" x 21.5"	1K	19" x 19" x 19"	10K	28 kgs

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